NSN 5962-01-204-4945

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-204-4945

view Online at https://defobasegroup.com/hist//3302-01-204-4343
Body Length:
Between 0.755 inches and 0.785 inches
Body Width:
Between 0.265 inches and 0.291 inches
Body Height:
Between 0.150 inches and 0.199 inches
Operating Tempurature Range:
55.0/+125.0 degrees celsius
Storage Tempurature Range:
65.0/+150.0 degrees celsius
End Application:
Computer-display set an/uyq-2 (v)
Features Provided:
Bipolar and high speed and programmed
nclosure Material:
Ceramic
nclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
nput Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level
putput
Memory Device Type:
Rom
Memory Capacity:
Jnknown
Test Data Document:
05869-726015-2 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

NSN 5962-01-204-4945

Memory Microcircuit - Page 2 of 2



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